

BD433/435/437

Medium Power Linear and Switching Applications

• Complement to BD434, BD436 and BD438 respectively



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|--|------------|-------|
| V_{CBO} | Collector-Base Voltage | | |
| | : BD433 | 22 | V |
| | : BD435 | 32 | V |
| | : BD437 | 45 | V |
| V _{CES} | Collector-Emitter Voltage | | |
| | : BD433 | 22 | V |
| | : BD435 | 32 | V |
| | : BD437 | 45 | V |
| V _{CEO} | Collector-Emitter Voltage | | |
| 020 | : BD433 | 22 | V |
| | : BD435 | 32 | V |
| | : BD437 | 45 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _C | Collector Current (DC) | 4 | Α |
| I _{CP} | *Collector Current (Pulse) | 7 | Α |
| I _B | Base Current | 1 | Α |
| P _C | Collector Dissipation (T _C =25°C) | 36 | W |
| TJ | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | - 65 ~ 150 | °C |

Electrical Characteristics $\rm T_{C}{=}25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|------------------------|--|--------------------------------------|------|------|------|-------|
| V _{CEO} (sus) | Collector-Emitter Sustaining Voltage | | | | | |
| | : BD433 | $I_C = 100 \text{mA}, I_B = 0$ | 22 | | | V |
| | : BD435 | | 32 | | | V |
| | : BD437 | | 45 | | | V |
| I_{CBO} | Collector Cut-off Current | | | | | |
| | : BD433 | $V_{CB} = 22V, I_{E} = 0$ | | | 100 | μΑ |
| | : BD435 | $V_{CB} = 32V, I_{E} = 0$ | | | 100 | μΑ |
| | : BD437 | $V_{CB} = 45V, I_{E} = 0$ | | | 100 | μΑ |
| I _{CEO} | Collector Cut-off Current | | | | | |
| | : BD433 | $V_{CE} = 22V, V_{BE} = 0$ | | | 100 | μΑ |
| | : BD435 | $V_{CE} = 32V, V_{BE} = 0$ | | | 100 | μΑ |
| | : BD437 | $V_{CE} = 45V, V_{BE} = 0$ | | | 100 | μΑ |
| I _{EBO} | Emitter Cut-off Current | $V_{EB} = 5V, I_{C} = 0$ | | | 1 | mA |
| h _{FE} | * DC Current Gain | | | | | |
| | : BD433/435 | $V_{CE} = 5V, I_{C} = 10mA$ | 40 | 130 | | |
| | : BD437 | | 30 | 130 | | |
| | : ALL DEVICE | $V_{CE} = 1V, I_{C} = 500 \text{mA}$ | 85 | 140 | | |
| | : BD433/435 | $V_{CE} = 1V, I_{C} = 2A$ | 50 | | | |
| | : BD437 | | 40 | | | |
| V _{CE} (sat) | * Collector-Emitter Saturation Voltage | | | | | |
| | : BD433 | $I_C = 2A, I_B = 0.2A$ | | 0.2 | 0.5 | V |
| | : BD435 | | | 0.2 | 0.5 | V |
| | : BD437 | | | 0.2 | 0.6 | V |
| V _{BE} (on) | * Base-Emitter ON Voltage | | | | | |
| | : BD433 | $V_{CE} = 1V$, $I_{C} = 2A$ | | | 1.1 | V |
| | : BD435 | | | | 1.1 | V |
| | : BD437 | | | | 1.2 | V |
| f _T | Current Gain Bandwidth Product | $V_{CE} = 1V, I_{C} = 250 \text{mA}$ | 3 | | | MHz |

^{*} Pulse Test: PW=300µs, duty Cycle=1.5% Pulsed

Typical Characteristics

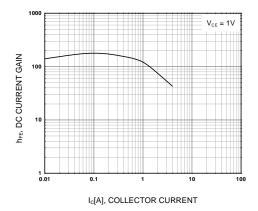


Figure 1. DC current Gain

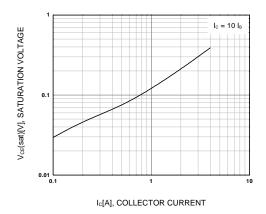


Figure 2. Collector-Emitter Saturation Voltage

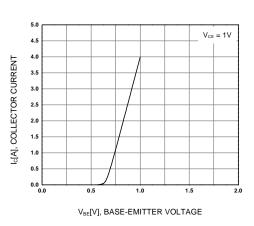


Figure 3. Base-Emitter On Voltage

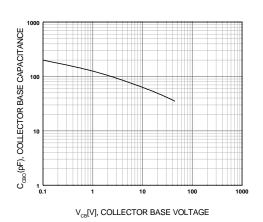


Figure 4. Collector-Base Capacitance

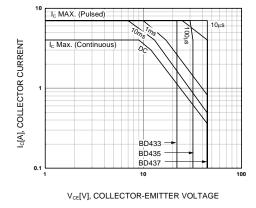


Figure 5. Safe Operating Area

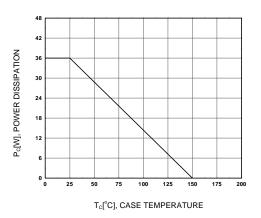
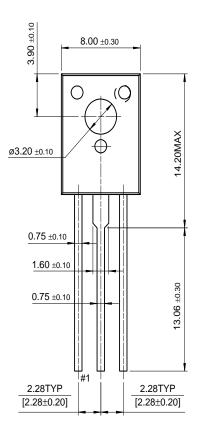


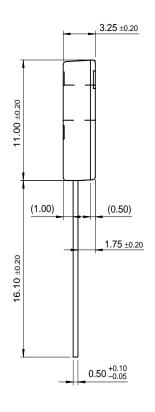
Figure 6. Power Derating

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Package Demensions

TO-126





Dimensions in Millimeters

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